NSN 5961-01-473-3343

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-473-3343 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.090 inches **End Application:** E/ifscm f-16aircraft Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.6 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 20.00 milliamperes all primaries horsepower metric and 117.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/533 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.

No Fiig: